BGU7044 1 GHz wideband low-noise amplifier Rev. 1 – 2 January 2012

Product data sheet

1. Product profile

1.1 General description

The BGU7044 MMIC is a 3.3 V wideband amplifier with internal biasing. It is designed specifically for high linearity, low-noise applications over a frequency range of 40 MHz to 1 GHz. It is especially suited for Set-Top Box applications.

The LNA is housed in a 6-pin SOT363 plastic SMD package.

1.2 Features and benefits

- Voltage supply of 3.3 V
- Internally biased
- Gain of 14 dB
- Flat gain between 40 MHz and 1 GHz
- Noise figure of 2.8 dB
- High linearity with an IP3_O of 29 dBm
- 75 Ω input and output impedance
- ESD protection > 2 kV Human Body Model (HBM) and > 1.5 kV Charged Device Model (CDM) on all pins

1.3 Applications

- Terrestrial Silicon and cable Set-Top Boxes (STB)
- Silicon and "Can" tuners
- Personal Video Recorders (PVR) and Digital Video Recorders (DVR)
- Home networking and in-house signal distribution



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1.4 Quick reference data

Table 1. Quick reference data

 $T_{amb} = 25 \ ^{\circ}C$; typical values at $V_{CC} = 3.3 \ V$; $Z_S = Z_L = 75 \ \Omega$; $R_{bias} = 18 \ \Omega$; 40 MHz $\leq f_1 \leq 1000 \ MHz$.

					-		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CC}	supply voltage	RF input AC coupled		3.1	3.3	3.5	V
I _{CC(tot)}	total supply current			30	34	38	mA
T _{amb}	ambient temperature			-40	-	+85	°C
NF	noise figure			-	2.8	-	dB
P _{L(1dB)}	output power at 1 dB gain compression	1 GHz		-	13	-	dBm
IP3 ₀	output third-order intercept point		[1]	-	29	-	dBm

[1] The fundamental frequency (f_1) is 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

Pinning information 2.

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	RF_OUT		
2	V _{CC}		\mathbf{N}^{3}
3	n.c.		6-1
4	n.c.		
5	GND	□1 □2 □3	5 4 sym141
6	RF_IN		,

Ordering information 3.

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
BGU7044	-	plastic surface-mounted package; 6 leads	SOT363				

Marking 4.

Table 4. Marking		
Type number	Marking code	Description
BGU7044	LJ*	* = p : made in Hong Kong
		* = W : made in China
		* = t : made in Malaysia

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5. Limiting values

Table 5. In accorda	Limiting values ance with the Absolute Ma	aximum Rating System (IEC 60134).				
Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage	RF input AC coupled		-0.6	3.5	V
I _{CC(tot)}	total supply current	configurable with external resistor		-	60	mA
P _{tot}	total power dissipation	$T_{sp} \le 100 \ ^{\circ}C$	[1]	-	250	mW
Pi	input power	single tone		-	20	dBm
T _{stg}	storage temperature			-65	+150	°C
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-40	+85	°C
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); according to JEDEC standard 22-A114E		2	-	kV
		Charged Device Model (CDM); according to JEDEC standard 22-C101B		1.5	-	kV

[1] T_{sp} is the temperature at the solder point of the ground lead.

6. Thermal characteristics

Table 6.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point		240	K/W

7. Characteristics

Table 7. Characteristics

 T_{amb} = 25 °C; typical values at V_{CC} = 3.3 V; Z_S = Z_L = 75 Ω ; R_{bias} = 18 Ω ; 40 MHz $\leq f_1 \leq$ 1000 MHz.

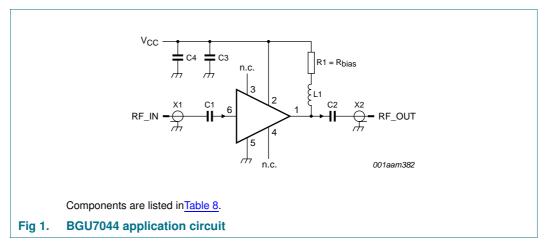
anno	, ,,		,	'		
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{CC}	supply voltage	RF input AC coupled	3.1	3.3	3.5	V
I _{CC(tot)}	total supply current		30	34	38	mA
$ s_{21} ^2$	insertion power gain		-	14		dB
SL _{sl}	slope straight line		-	-1	-	dB
FL	flatness of frequency response		-	0.2	-	dB
NF	noise figure		-	2.8	-	dB
RL _{in}	input return loss		-	20	-	dB
RL _{out}	output return loss		-	12	-	dB
P _{L(1dB)}	output power at 1 dB gain compression	1 GHz	-	13	-	dBm
IP3 ₀	output third-order intercept point		<u>1</u>] -	29	-	dBm

[1] The fundamental frequency (f₁) is 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

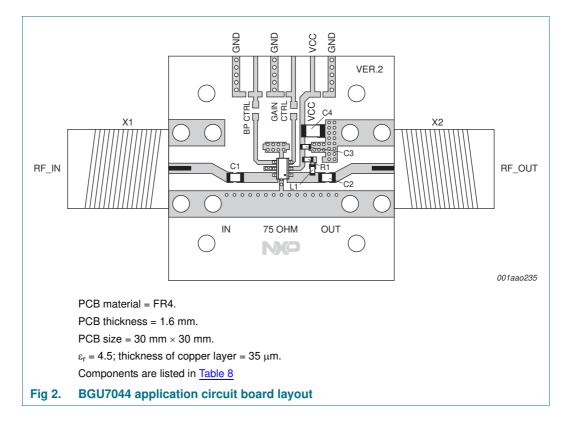
8. Application information

Other applications are possible. Please contact your local sales representative for more information. Application notes are available on the NXP website.

8.1 Application circuit



All control and supply lines must be decoupled properly. The decoupling capacitors must be placed as close to the device as possible.



8.2 Application circuit board layout

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Table 8.List of componentsSee Figure 1 and Figure 2

and <u>Figure 2</u>			
Description	Value	Remarks	Function
capacitor	10 nF		DC blocking
capacitor	10 nF		decoupling
capacitor	10 μF		decoupling
chip ferrite bead	1.5 kΩ	1 Murata BLM18HE152SN1DF	RF choke
resistor	18 Ω	[1] R _{bias}	bias setting
connector	75 Ω	F-connector, edge mount PCB reflow type, Bomar 861V509ERG	input/output
	Description capacitor capacitor capacitor chip ferrite bead resistor	Description Value capacitor 10 nF capacitor 10 nF capacitor 10 μF capacitor 15 kΩ resistor 18 Ω	DescriptionValueRemarkscapacitor10 nFcapacitor10 nFcapacitor10 μFchip ferrite bead1.5 kΩfersistor18 Ωfersistor18 Ωconnector75 ΩF-connector, edge mount PCB

[1] L1 and R1 must have a power rating of 0.1 W or higher.

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9. Package outline

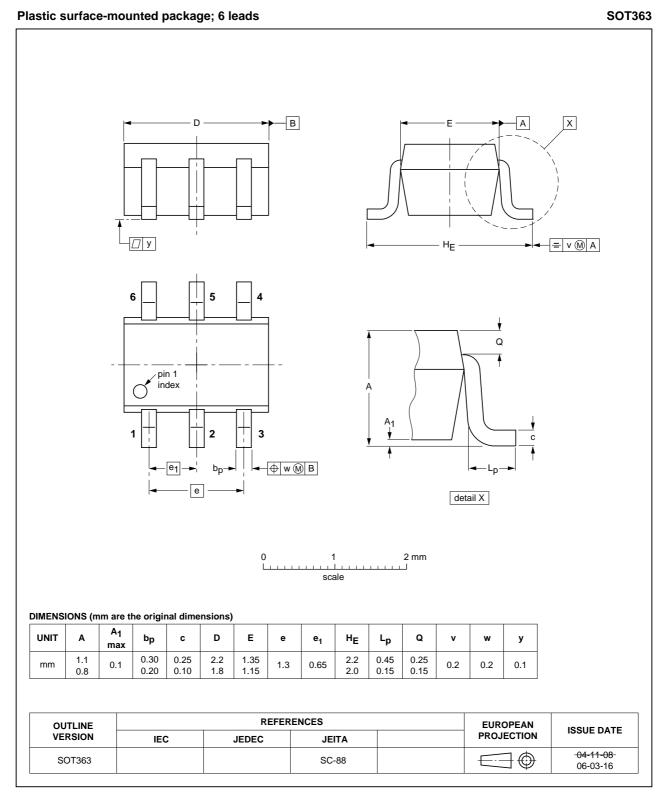


Fig 3. Package outline SOT363

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10. Abbreviations

AC A DC D ESD E LNA LC	Description Iternating Current Direct Current
DC D ESD EI LNA Lo	
ESD EI	Virect Current
LNA Lo	
	lectroStatic Discharge
	ow-Noise Amplifier
MMIC M	Ionolithic Microwave Integrated Circuit
PCB Pr	rinted-Circuit Board
RF R	adio Frequency
SMD S	Surface-Mounted Device

11. Revision history

Table 10. Revision hist	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BGU7044 v.1	20120102	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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